# **RPI-579N1**

## Photointerrupter, General type

### Absolute maximum ratings (Ta=25°C)

	Parameter	Symbol	Limits	Unit
Input (LED)	Forward current	lF	50	mA
	Reverse voltage	VR	5	V
	Power dissipation	Po	80	mW
Output (photo- (transistor)	Collector-emitter voltage	Vceo	30	V
	Emitter-collector voltage	Veco	4.5	V
	Collector current	lc	30	mA
	Collector power dissipation	Pc	80	mW
Operating temperature		Topr	-25 to +85	°C
Storage temperature		Tstg	-40 to +85	°C
	Soldering temperture	Tsol	260 / 3 *	°C / s

\* 1mm from the body bottom.

#### Electrical and optical characteristics (Ta=25°C)

Parameter			Symbol	Min.	Тур.	Max.	Unit	Conditions
Input charac- teristics	Forward voltage		VF	-	1.3	1.6	V	I⊧=50mA
	Reverse current		IR	-	-	10	μΑ	VR=10V
Output charac- teristics	Dark current		ICEO	-	-	0.5	μΑ	Vce=10V
	Peak sensitivity wavelength		λρ	-	800	-	nm	-
Transfer characteristics	Collector current		lc	0.5	-	-	mA	Vce=5V, IF=20mA
	Collector-emitter saturation voltage		VCE(sat)	-	0.1	0.5	V	IF=20mA, Ic=0.1mA
	Response time	Rise time	tr	-	10	-	μs	Vcc=5V, IF=20mA, RL=100Ω
		Fall time	tf	-	10	-	μs	
Infrared light emitter diode	Cut-off frequency		fc	-	1	-	MHz	Ir=50mA
	Peak light emitting wavelength		λρ	-	950	-	nm	* Non-coherent Infrared light emitting diode used.
Photo transistor	Response time		tr • tf	-	10	_	μs	$\label{eq:Vcc=5V, lc=1mA, Rl=100\Omega} $$ $$ This product is not designed to be protected against electromagnetic wave. $$$
	Maximum sensitivity wavelength		λp	I	800	-	nm	-

### Electrical and optical characteristics curves

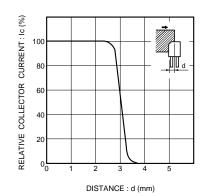


Fig.1 Relative output vs. distance (I)

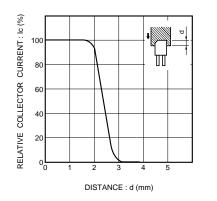


Fig.4 Relative output vs. distance (II)

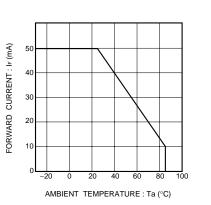
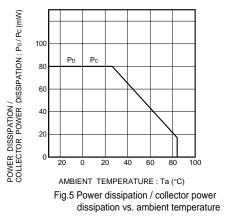
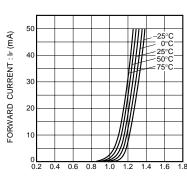


Fig.2 Forward current falloff





Applications

AV equipment

Features

3) Quick response time.

2) Small gap (0.5mm) and good accuracy.

4) Filter against visible ray is built-in.5) Kinked forming.

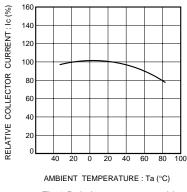
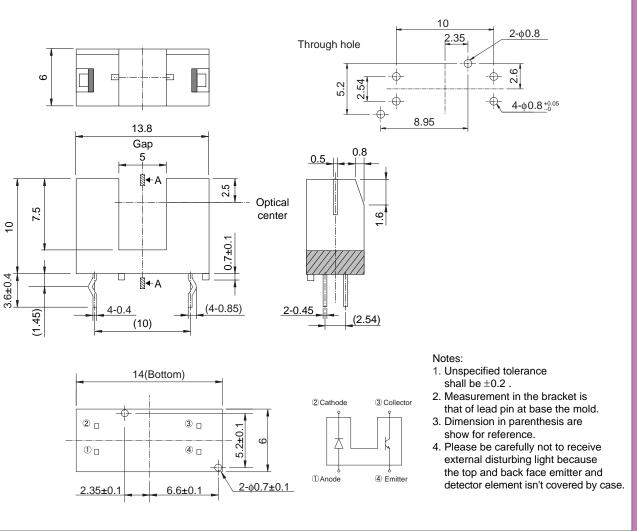


Fig.6 Relative output vs. ambient temperature

External dimensions (Unit : mm)



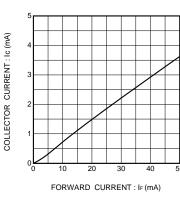
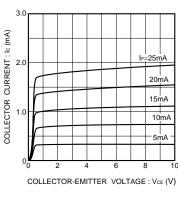


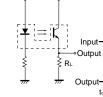
Fig.7 Collector current vs. forward current



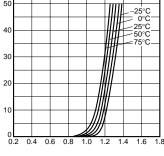
R 50 100 200 500 20 COLLECTOR CURRENT : Ic (µA) Fig.8 Response time vs. collector current Input Vcc

IIME

ONSE



td: Delay time tr: Rise time (time for output current to rise from 10% to 90% of peak current) tr: Fall time (time for output current to fall from 90% to 10% of peak current)



FORWARD VOLTAGE : VF (V)

Fig.3 Forward current vs. forward voltage





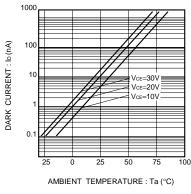


Fig.9 Dark current vs. ambient temperature

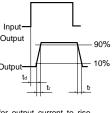


Fig.11 Response time measurement circuit

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